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Projection exposure lens with aspheric elements (54)

The invention relates to a projection exposure (57)lens with

an object plane, optical elements for separating beams,

a concave mirror,

an image plane,

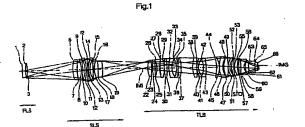
a first lens system arranged between the object plane and the optical elements for separating beams.

a second double passed lens system arranged between the optical elements for separating beams and the concave mirror, and

a third lens system arranged between the optical elements for separating beams and the image

The Invention is characterized in that

at least one of the lens or mirror surfaces of the first, second or third lens system is aspheric and the numerical aperture NA of the projection exposure lens is 0,7 or greater, preferably 0,8 or greater with a maximum image height exceeding 10mm.



Description

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1. Field of the invention

[0001] The present invention relates to a projection exposure lens in a projection exposure apparatus such as a wafer scanner or a wafer stepper used to manufacture semiconductor elements or other microstructure devices by photolithography and, more particularly, to a catadioptric projection optical lens with an object side catadioptric system and a refractive system for use in such a projection exposure apparatus.

2. Related Background Art

[0002] US 4,779,966 to Friedman gives an early example of such a lens, however the catadioptric system being arranged on the image side. Its development starting from the principle of a Schupmann achromat is described. It is an issue of this patent to avoid a second lens material, consequently all lenses are of fused silica. Light source is not specified, band width is limited to 1 nm.

[0003] US 5,052,763 to Singh (EP 0 475 020) is another example. Here it is relevant that odd aberrations are substantially corrected separately by each subsystem, wherefore it is preferred that the catadioptric system is a 1:1 system and no lens is arranged between the object and the first deflecting mirror. All examples provide only fused silica lenses. NA is extended to 0.7 and a 248 nm excimer laser or others are proposed. Line narrowing of the laser is proposed as sufficient to avoid chromatic correction by use of different lens materials.

[0004] US 5,691,802 to Takahashi is another example, where a first optical element group having positive refracting power between the first deflecting mirror and the concave mirror is requested. This is to reduce the diameter of the mirror, and therefore this positive lens is located near the first deflecting mirror. All examples show a great number of

[0005] EP 0 736 789 A to Takahashi is an example, where it is requested that between the first deflecting mirror and the concave mirror three lens groups are arranged, with plus minus plus refractive power, also with the aim of reducing the diameter of the concave mirror. Therefore, the first positive lens is located rather near to the first reflecting mirror. Also many CaF₂ lenses are used for achromatization.

[0006] DE 197 26 058 A to Omura describes a system where the catadioptric system has a reduction ratio of 0.75 $\leq \beta_1 \leq 0.95$ and a certain relation for the geometry of this system is fulfilled as well. Also many CaF₂ lenses are used

[0007] For purely refractive lenses of microlithography projection exposure system a lens design where the light beam is twice widened strongly is well known, see e.g. Glatzel, E., Zeiss-Information 26 (1981), No. 92, pages 8-13. A recent example of such a projection lens with + - + - + lens groups is given in EP 0 770 895 to Matsuzawa and Suenaga. [0008] The refractive partial objectives of the known catadioptric lenses of the generic type of the invention, however,

show much simpler constructions. [0009] A catadioptric projection exposure lens comprising lenses or mirrors which are aspheric are known from JP 10-10429 and EP 0 869 383.

[0010] According to JP 10-10429 the aspheric surface is placed in the vicinity of a reflecting mirror.

[0011] By placing the aspheric surface in vicinity of the reflecting mirror, a good correction of distortions is achieved. Furthermore the system according to JP 10-10429 comprises an intermediate image.

[0012] From EP 0 869 383 a catadioptric system comprising at least two aspheric surfaces is known. For correcting off-axis-aberration one of the aspheric surfaces satisfies the condition

 $h/\phi < 0.85$

and for correcting on-axis-aberration the other of the aspheric surfaces satisfies the condition

0.85 < h/φ < 1.2. . ~

whereby h is the height at each lens surface of the light beam that is assumed to be emitted from the intersection of the optical axis and the object plane and passes through the lens surfaces with the maximum numerical aperture NA and ϕ is the radius of the diaphragm of the aperture stop. Subject matter of EP 0 869 383 therefore is to ensure a high image quality by using aspheric surfaces.

[0013] Only as a point amongst others EP 0 869 383 mentions that by using aspheric surfaces the number of lenses in a catadioptric system can be decreased. Furthermore EP 0 869 383 relates only to systems with an intermediate

Image. As special embodiments EP 0 869 383 shows systems with the first aspheric surface placed near the intermediate image while the second aspheric surface is placed near the concave mirror of the catadioptric system or near the aperture stop.

[0014] WO 99/52004 shows embodiments of catadioptric objectives with few lenses, some of them being aspheric. From WO 99/52004 a system with 16 lenses, at least four of them being aspheric lenses and a numerical aperture of 0.65 is known.

[0015] From E. Heynacher, Zeiss-Information 24, pp. 19- 25 (1978/79), Heft 88, it is known that with complicated optical systems it is less appropriate to treat imaging errors separately by aspheres, but to influence the correction of the imaging errors as a whole.

3. Summary of the Invention

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[0016] It is an object of the present invention to obtain a catadioptric optical system of new construction principles allowing for large numerical aperture, large image field, sufficient laser bandwidth, solid and stable constructions, which takes into account the present limitations on availability of CaF₂ in quantity and quality. Therefore it is the major object of the present invention to minimize the number of lenses in a projection exposure lens for DUV (193 nm) and VUV (157 nm) systems. Furthermore said systems should not be restricted to systems with an intermediate image.

[0017] In order to achieve the above object, according to the present invention, there is provided a projection exposure lens according to claim 1.

[0018] It is a further object of the invention by minimizing the number of lenses to reduce the absorption and the reflection losses of the whole projection exposure lens.

[0019] Said further object is achieved by reducing the number of lenses in the second double passed lens system of the projection exposure lens since in the double passed lens system undesirable effects of absorption in the lens material and of reflection losses at the surface count twice.

[0020] According to the invention the second lens system comprises at maximum five lenses, preferably two or three

[0021] In a preferred embodiment of the invention negative refraction power is arranged in the second lens system between the optical elements for splitting beam and the concave mirror. Said negative refraction power is split into advantageously two negative lenses.

[0022] In a further preferred embodiment for correcting the chromatic length aberration CHL the second lens system provides for a over correction while the first and third lens system provides for a under correction.

[0023] The long drift section in the second lens system according to the invention provides for several advantages:

- Mounting of the lens components in the second lens system is less complicated than in objectives known from the prior art.
- The lenses of the second lens system and the concave mirror could be mounted as a separate lens group, no
 metallic tube is necessary between the optical elements for splitting beam and the first lens of the second lens
 system.

[0024] Further advantageous embodiments are obtained when including features of one or more of the dependent claims 4 to 61.

[0025] An advantageous projection exposure apparatus of claim 62 is obtained by incorporating a projection exposure lens according to at least one of claims 1 to 61 into a known apparatus.

[0026] A method of producing microstructured devices by lithography according to the invention is characterized by the use of a projection exposure apparatus according to the preceding claim 62. Claim 63 gives an advantageous mode of this method.

[0027] The present invention will be more fully understood from the detailed description given hereinbelow and the accompanying drawings, which are given by way of illustration only and are not to be considered as limiting the present invention. Further scope of applicability of the present invention will become apparent from the detailed description given hereinafter. However, it should be understood that the detailed description and specific examples, while indicating preferred embodiments of the invention, are given by way of illustration only, since various changes and modifications within the spirit and scope of the invention will be apparent to those skilled in the art from this detailed description.

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4. Brief Description of the Drawings

[0028]

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5	Figure 1	is a section view of the lens arrangement of a first embodiment;
	Figure 2	is a section view of the lens arrangement of a second embodiment;
	Figure 3	is a section view of the lens arrangement of a third embodiment;
10	Figure 4	is a section view of the lens arrangement of a fourth embodiment;
	Figure 5	is a section view of the lens arrangement of a fifth embodiment;
15.	Figure 6	is a section view of the lens arrangement of the sixth embodiment; and
	Figure 7	is a section view of the lens arrangement of the seventh embodiment;
	Figure 8	is a section view of the lens arrangement of a eighth embodiment;
20	Figure 9	is a section view of the lens arrangement of a ninth embodiment;
	Figure 10	is a section view of the lens arrangement of a tenth embodiment;
25	Figure 11	is a view of an alternative arrangement of the folding mirrors.

[0029] First a projection exposure apparatus in which an projection exposure lens according to the invention could be used is described without showing a figure thereof. A projection exposure apparatus includes for example an excimer laser light source with an arrangement moderately narrowing bandwidth. An illumination system produces a large field, sharply limited and illuminated very homogeneously, which matches the telecentricity requirements of the projection lens, and with an illumination mode to choice. Such mode may be conventional illumination of variable degree of coherence, annular or quadrupole illumination.

[0030] A mask or a reticle is displaced in the illuminated area by a mask resp. reticle holding and handling system which includes the scanning drive in case of a wafer scanner projection exposure apparatus. Subsequently follows the projection exposure lens according to the invention to be described in detail subsequently.

[0031] The projection exposure lens produces a reduced scale image of the mask on a wafer. The wafer is held, handled and eventually scanned by a scanning unit.

[0032] All systems are controlled by control unit. Such unit and the method of its use is known in the art of microlithographic projection exposure.

[0033] However, for exposure of structures in the regime of about 0.2 µm and less resolution at high throughput there is a demand for various projection exposure lenses capable to be operated at 193 nm, eventually also at 248 nm or 157 nm excimer laser wavelengths with reasonably available bandwidths (e.g. 15 pm at 193 nm), at high image side numerical aperture of 0.65 to 0.8 or more and with reasonably large rectangular or circular scanning image fields of e. g. 7 x 20 to 10 x 30 mm².

[0034] This design concept can be easily modified for 126 nm wavelength with appropriate lens material, e.g. LiF.

Systems according to the state of the art cited above are in principle suitable for this.

However, according to the invention a number of measures and features has been found to improve these [0036]

[0037] The example shown in the sectional view of figure 1 has the lens data given in Table 1 in code-V-format in the annex and makes use only of fused silica lenses. As only one lens material is used, this design can easily be adapted for other wavelengths as 248 nm or 157 nm. The numbers for the objects in table 1 are identical to the reference

[0038] The intermediate image IMI is freely accessible, so that it is easily possible to insert a field stop. The aperture stop STO is also well accessible.

[0039] The splitting of the beam in the catadioptric system is not shown in the embodiments depicted in figures 1 -7. Beam splitting can be achieved e.g. by a physical beam splitter, e.g. a beam splitter prism as disclosed in US 5,742,436. The content of this document is enclosed fully herewith.

[0040] An alternative is the usage of deflecting mirrors. In such an embodiment the deflecting mirrors in the catadi-

optric system are defined in their geometry by the demands of separation of the light beams to and from the concave mirror 12 and of clearance from the lenses.

[0041] The arrangement of two deflection mirrors allows for a straight optical axis and parallel situation of origin plane 0 and image plane IMG, i.e. mask resp. reticle and wafer are parallel and can easily be scanned. However, one of the deflecting mirrors can be abandoned or eventually be replaced by a deflecting mirror in the third lens system TLS which is a refractive lens. It is also clear that the deflecting mirrors can be replaced by other deflecting optical elements, e. g. prisms.

[0042] A moderate positive lens comprising surfaces 2, 3 is placed near the origin plane 1 in the first lens system FLS, which is a single beam area. Its focal length is approximately equal to its distance from the concave mirror 13.

[0043] This makes that the concave mirror 13 is situated in a pupil plane and thus the diameter required is minimized. [0044] A further positive lens is located as a first lens with surfaces 6, 7 in the second doubly passed lens system SLS consisting of three lenses with surfaces 6, 7, 8, 9, 10, 11. As the production conditions of concave mirrors of 200 mm to 300 mm diameter give no strong preference to smaller units - in contrast to lenses, namely such made from CaF₂, where inhomogeneties etc. give strong limitations - there is no need to use this positive lens with surfaces 6, 7 for reduction of the radius of the concave mirror 100.

[0045] The two negative lenses with surfaces 8, 9, 10, 11 of the second lens system SLS cooperate with the concave mirror 13 in a known manner, giving increased angles of incidence and stronger curvature, thus stronger correcting influence of the concave mirror 13.

[0046] It is significant, that the number of lenses in the doubly passed area of the catadioptric system is restricted to a low number, e.g. three as in this embodiment, since in this part of the optical system every lens counts double with respect to system energy transmission and wavefront quality degradation - without giving more degrees of freedom for correction.

[0047] The embodiment according to figure 1 comprises only one aspheric surface 9, 16 in the double passed second lens system SLS of the projection exposure lens. The aspheric surface 9, 16 is situated on the wafer or image IM-side of the lens comprising said surface.

[0048] At the intermediate image plane IMI preferably a field stop is inserted, which reduces stray light favourably.

[0049] The third lens system TLS following the intermediate image IMI is in principle known from the art. In the embodiment shown the third lens system does not comprise any aspheric surface. The details of the design are given in table 1 in code V-format in the annex of the application.

[0050] The example of the invention according to figure 1 with an image side NA = 0.70 is suitable for printing microstructures at a resolution of less than 0.2 μ m over an image field of 30 x 7 mm² rectangle at 6 mm off axis, with an excimer laser source of 0.015 nm bandwidth.

[0051] Figure 2 and table 2 show a design variant. The second lens system SLS comprises in total four lenses with surfaces which are passed twice. In contrast to the embodiment according to figure 1 the aspheric surface 160 is situated in the third lens system TLS facing towards the image IMG resp. the wafer. The details of this embodiment are given in table 2 in code-V-format in the annex. The numbers for the objects in table 2 are identical to the reference signs in figure 2.

[0052] Figures 3 and 4 and tables 3 and 4 in the annex show other examples of a projection exposure lens according to the invention. As in the antecedent example, all have an image side NA = 0.70. Furthermore the number of the objects in table 3 and 4 correspond to the reference numbers in the figures 3 and 4.

[0053] Now, the catadioptric system comprising the second lens system and the concave mirror shows a major revision, since the aspheric surface is situated on the concave mirror 211. This allows for reducing the number of lenses in the catadioptric system to a total number of three. Only the two negative lenses with surfaces 206, 207, 208, 209 have to be passed twice.

[0054] In the embodiment according to figure 3 the projection exposure lens comprises only one aspheric surface, whereas in the embodiment according to figure 4 a further aspheric surface is situated in the third lens system TLS. The further aspheric surface in the third lens system faces towards the image IMG resp. the wafer. The details of these embodiments are given in Tables 3 and 4 in code-V-format in the annex.

[0055] A fifth embodiment is given in figure 5 and table 5.

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[0056] Now, aspheric surfaces are situated only in the third lens system.

[0057] Details of the system are given in Table 5 in code-V-format in the annex. The number of the objects in table 5 correspond to the reference number in figure 5.

[0058] In the sixth embodiment of the invention shown in figure 6 the aspheric surfaces are situated in the third lens system on surface 533, 539 far away from the intermediate image IMI and in the second lens system SLS. In this embodiment the concave mirror 513 of the second lens system comprises an aspheric surface.

[0059] Details of the system are given in Table 6 in code-V-format in the annex. The number of the object in table 6 correspond to the reference number in figure 6.

[0060] In the seventh embodiment of the invention shown in figure 7 the aspheric surfaces are situated in the third

lens system TLS on surface 631, 637, 648 far away from the intermediate image IMI as in embodiment 6 and in the first lens system on surface 603. In contrast to embodiment 6 the aspheric surface of the first lens system is situated on a lens near the object 0 resp. reticle instead on the concave mirror.

[0061] Details are given in table 7 in code-V-format in the annex. The number of the object in table 7 corresponds to the reference number in figure 7.

[0062] WO 99/52004 cited in the inductory part of this application shows that with a generic catadioptric objective image side numerical apertures of up to 0.65 can be obtained with less than 16 lenses when entering at least 4 aspherical lenses.

[0063] The invention shows that increased resolution capabilities with numerical apertures of 0.7 to 0.85 and more, at unrestricted image fields and with state of the art correction, are obtained with lesser aspheres in the 0.7 NA range. With the number of 16 lenses and one aspherical surface per lens and on the concave mirror even 0.85 NA is demonstrated as compared to 0.65 NA with 8 aspherical surfaces of 10 lenses and one planar plate of example 4 of the cited WO 99/52004-application.

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[0064] It is advantageous that between the object plane and the doubly passed group of lenses as a first lens system at least one lens is inserted, preferably exactly one. This could be a positive lens. It optimizes object side telecentricity. Aspherization of this lens, bending it to a meniscus, and aspherizing the concave surface are particularly preferred measures. Preferably, too, its object side surface has the smaller radius of curvature.

[0065] This lens of the first lens system FLS is also predestined to be used for implementation of correcting surfaces, which may be free-form aspheric surfaces, as it is easily accessible also after complete assembly of the lens.

[0066] It is also a very significant finding of the inventors, that this first lens system can be shifted off-axis, with its axis of symmetry arranged between the center of the object field and the optical axis. This allows for a rather symmetric illumination system as conventional with on-axis scanning systems. Generally, in this lens design effort is taken to keep the object side telecentricity very good. So even with the off-axis object field necessitated by the catadioptric design, the illumination system can be rotationally symmetric to the center of the object field, what allows for clearly reduced diameter of this system and consequently great cost reduction.

[0067] Also the optical axis in the region of this first lens system can be shifted with respect to the parallel optical axis of the refractive partial system, away from the concave mirror. This allows for a better division of the illuminated areas on the two folding mirrors arranged nearby in the preferred variations of the invention. This offset is 2.95 mm in the examples of Fig. 5, 6 and 7 and is 17.5 mm in the NA = 0.85 example of Fig. 8 and 12.5 mm in the NA = 0.75 example of Fig. 9. The details of the embodiments of Fig. 8 and Fig. 9 are given in table 8 and table 9 in code-V-format in the annex. The number of the object in tables 8 and 9 correspond to the reference number in figures 8 and 9.

V-format in the annex. The number of the object in table 10 corresponds to the reference number in figure 10. The tenth embodiment is a 5x reduction system with a magnification ratio of -0.2. The image side aperture is NA = 0.80. The projection lens comprises 17 lenses, one concave mirror 1012 and a planar protecting plate 1050/1051. All lenses are made of Calcium Fluoride (CaF₂). Eight lenses in the third lens system comprise an aspherical surface whereas all lenses in the second lens system and the concave mirror are spherical lenses. The rectangular field has the dimensions 22 mm to 7 mm in the image plane IMG, wherein the center of the field is arranged 4.62 mm off axis from the optical axis OA3 of the third lens system TLS. The projection lens is optimized for a wavelength of 157.63 nm +/- 0.6 pm. The polychromatic wavefront aberration shows a maximum of 10 milliwaves at all field heights, the monochromatic wavefroit aberration shows a maximum of 10 milliwaves at all field heights, the monochromatic wavefroit aberration shows a maximum of 1009, 1010, 1011 and the axis OA1 of the first lens group is 104°. Therefore all light beams at the lenses of the double pass second lens system and the concave mirror 1012 are more distant from the object plane O than the first lens of the first lens group from the object plane is.

[0069] Fig. 11 shows an alternative arrangement of the folding mirrors M1' and M2', where they do not share a common ridge. Here even stronger axis shift is needed. The construction length between object and image can be reduced in this way, and new compromise possibilities in passing by of the light beams at the folding mirrors are opened.

[0070] The folding mirrors of the other shown examples are conveniently established on a common prism substrate.

[0071] Alternatively, the folding mirrors can be internal surfaces of prisms passed by the light beam. The higher refractive index of prism material - i.e. calcium fluoride, other crystals, quartz glass or other optical glass - then allows for more compact transfer of high aperture beams.

[0072] Advantageously they are coated with reflection enhancing thin films, which can even more advantageously correct variations in phase shifts caused by reflections under different angles by adapted thicknesses.

[0073] Also, the folding mirrors can be formed with slight aspheric - non-rotationally symmetric, free-form surface forms for correction of these phase effects as well as other tiny errors of imaging of the system or of production tolerances.

[0074] The preferred configuration of the invention differs from the cited art in that the double pass lens second lens system and concave mirror are arranged along an unfolded optical axis, with two folding mirrors in the region, where

the optical axis of this subsystem crosses with those of the first lens group and the refractive partial objective. The folding angle between the optical axis of the double pass second lens system and the other axes advantageously deviates from 90° such that at the lenses and the mirror all light beams are more distant from the object plane than the first lens surface of the first lens group is. Consequently, the necessary free access to the object plane needed for scanning does not interfere with the space needed for the mounts of the optical elements.

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[0075] A further issue of the invention lies in the design of the double pass lens group having a minimal number of lenses. Each degree of freedom for correction of the imaging obtained by an additional lens here has twice the undesirable effects of absorption in the lens material and of reflection losses at the surfaces. Consequently only the lenses needed for putting into effect the concave mirror, for separating the light bundles at the folding mirrors and for keeping the length of the side arm established by the double pass group relatively short are provided.

[0076] In the examples shown the intermediate image IMI directly follows after the folding mirror arranged subsequent to the double path lens group. Though the space between this folding mirror and the intermediate image tends to be narrow, one or other lens can well be introduced here.

[0077] The lenses arranged after and near the intermediate image IMI are illuminated by light bundles situated strongly off axis, so that lens heating caused by light absorption leads to strongly asymmetric disturbing effects. Consequently, the number of lenses in this space is kept low, with normal forms and thicknesses to keep these lens heating influences low.

[0078] Aspherization of the lens next to the intermediate image is strongly suggested by EP 0 869 383. However, besides the above named asymmetry effect, there are further aspects making this less preferable. Once, the intermediate image is per its function in the objective badly corrected, so that the named separation of field specific image errors is disrupted.

[0079] Then, e.g. from E. Heynacher, Zeiss-Inform. 24, 19-25 (1978/79) Heft 88, it is long known that with complicated optical systems it is less appropriate to treat the imaging errors separately by aspheres, but to influence the correction of all imaging errors as a whole. Consequently it is preferred to distribute the aspheres onto lens surfaces of different relative influences to the relevant imaging errors.

[0080] Especially, the effect of aspherization of the first lens at the object side shows stronger influence onto distortion than a lens very near to the intermediate image can have.

[0081] EP 0 869 383 gives another condition for aspherical surfaces, namely $0.85 < h/\phi < 1.2$, which is of less relevance, as shown by the example of Fig. 9 and table 9. Here this parameter is for the aspheric surfaces 803 = 0.09, 811 = 1.22, 813 = 1.23, 834 = 0.84, 844 = 0.70, 849 = 0.14. Consequently, it is advantageous for the correction of high NA objectives of this sort, if one or more aspheric surfaces features this parameter $h/\phi > 1.2$.

[0082] Also here the novel concept of using aspherical surfaces situated oppositely, separated by a narrow air space, is introduced at the aspherical concave mirror 813 and the opposing surface 811 of the neighboring negative meniscus. This is contrary to the concept of one asphere per error to be corrected and allows for more precise influencing of the correction state of an objective - also in other optical concepts.

[0083] In the refractive partial objective a long drift space intermediate the intermediate image IMI and the aperture stop STO is typical, while the space between aperture stop STO and image plane IMG is densely packed with lenses. A meniscus concave versus the aperture stop STO, establishing a positive air lens with the neighboring lens is a typical correcting element introduced in previous applications of the inventors. This concave surface (844 in Fig. 9) is also a very effective location of an aspheric surface. Preferably this or other asphere in the space between aperture stop STO and image plane IMG is paired by an asphere (834 in Fig. 9) arranged approximately symmetrically on the other side of the aperture stop STO.

[0084] In the high numerical aperture applications of the invention also the most image-sideward lens is advantageously aspherized, namely on its image side, as surface 849 in Fig. 9 and as surface 749 in Fig. 8. Here the greatest incidence angles of the light rays occur and give special influence of the aspherics here.

[0085] Ongoing acceleration of the semiconductor roadmap forces the industry to extend optical lithography much further than ever expected. Including 157 nm wavelength radiation, today it is believed that optical lithography could even enable manufacturing at the 70 nm node of resolution under commercial conditions. The 50 nm node would require at least 157 nm optics with extremely high numerical apertures (>0.8). Extending wavelength further down to 126 nm (Ar₂-laser), would only help if optics (mirrors and a few transmittive, refractive lens elements, preferably LiF lens elements) can achieve numerical apertures well above 0.7. Translating the semiconductor roadmap into an exposure tool roadmap, not only new wavelengths are needed, but also extremely high NA optics will be introduced. To assure high enough process latitude, resolution enhancement methods will be implemented in volume manufacturing. Next to advanced mask technology, layer-tailored illumination schemes will be used.

[0086] As such illumination with linearly polarized light and with a quarter-wave plate at the aperture stop plane for image-side circularly polarized light is advantageous. An alternative can be radially polarized light as described in DE 195 35 392 A (US ser. No. 08/717902) of the same assignee.

[0087] Such high numerical aperture objectives are provided by the invention, with Fig. 8 and table 8 giving the

extreme image side numerical aperture NA = 0.85 at 5x reduction, with a 22 mm x 7 mm slit scanning image field, ± 0.6 pm laser bandwidth at the 157.1 nm excimer laser line, with all lenses made from calcium fluoride crystal. Naturally, at this elevated demand for correction, the limit of 15 lenses given in WO 99/52004 with examples of moderate NA = 0.65, is exceeded - but only by one additional lens, at 9 aspherical surfaces. Polychromatic wavefront aberration shows a maximum of 20 milliwaves at all field heights - a reasonably good imaging quality at these conditions.

[0088] The embodiment of Fig. 9 and table 9 features at 5x reduction imaging with a 22 mm x 7 mm image field at 157.1 nm ± 0.6 pm with the high image side NA = 0.75. The 16 lenses and 1 concave mirror obtain this at a wavefront

error of maximal rms of 21 milliwaves with only 5 aspherical surfaces as described above.

[0089] If preferred for reasons of gas purging at the reticle or wafer, the object side as well as the image side of such objectives can be a planar surface, either by introducing a planar protecting plate as is in widespread use, e.g. in WO 99/52004, or by changing design under the restriction of a planar face.

[0090] The invention covers all the combinations and subcombinations of the features give in this specification and

the claims, drawings and tables.

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[0091] While examples are given for the scanning scheme of exposure, the invention as well is useful with step-andrepeat or stitching. Stitching allows for specifically smaller optics.

Annex: Code-V-tables of the objectives shown in fig. 1-10

table 1: wavelength = 193,31 nm

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	Object	Radius	Thickness RMI)	Glass sort		
10							
			:·· ·				
	> OBJ:	INFINITY	0.000000				÷
	1:	INFINITY	35.000000		_		
15	2:	534.41573	16.000000 .		'S102HL'		•
		-2605.52657	82.000000				
	4:	INFINITY	423.377560		·*		
	5:	INFINITY	0.00000				•
	6:	524.08780	50.000000		'SIO2HL'		
	7;	903.54667	44.861212				
?0	8:	-263.10576	15.000000		'SIO2HL'		
, '		-1376.18978	33.775444				••
	ASP:						
•	к :	0.000000					
	IC:	YES	CUF: 0.000000	_		_	0 00000000000
OF.	. A :0	.983295E-10	B :0.156925E-14	С	:0.660351E-20	Q	:0.000000E+00
25			15.000000		'SIO2HL'		
	10:	~209.43665	12.442047		0202111		-
	11:	-400.74819	0.000010	REFL			
	12:	INFINITY	12.442047	REFL			
	13:	278.05481		KEFU	'SIO2HL'		
30	14:	400.74819	15 -000000 33 -775444-		3101111		• .
30	15:	209.43665	15.000000		'SIO2HL'		-
	16:	1376.18978	15.00000	•	STOPHE		
	ASP:						
	K :	0.000000	CUE: 0.000000				
	IC:	YES		C	:660351E-20	ם	:0.000000E+00
35	A :-	.983295E-10	B :156925E-14	C	:0003311 20	-	
	17:.	263.10576	44.861212				
	18:	-903.64667	- 50.000000	·	'SIO2HL'		
	19:	-524.08780	449.719482				
	20:	INFINITY	0.00000		• .		
	21:	INFINITY	63.778860		•		
40	22:	367.04203	39.381898		'SIO2HL'		
	23:	-813.93537	12.355245				
	23. 24:	862.20789	26.902539		'SIO2HL'		
	25:	-2189.11598	19.271290				
	26:	-280.32916	23.514083		'SIO2HL'		
15	27:	551.01352	7.025237				
45	28:	1073.23821	46.193223		'SIO2HL'		
	۷۵.						

Annex: Code-V-tables of the objectives shown in fig. 1-10

table 1: wavelength = 193,31 nm

10	Object	Radius	Thickness RMD	Glass sort
				•
		·	•	-
	00.	393 - 66672	1.000000	
15	29: 30:	942.86330	31.837703	'SIO2HL'
	31:	-734.28385	17.595477	
	32:	471.84849	34.925052	, SIOSIIT,
	33:	223.32640	54.276947	
	34:	-238.14826	16.480387	'SIO2HL'
20	35:	-432.42551	1.000000	1.57.03117 /
	36:	846.35305	38.186692	'S10211L'
	37:	-382.59164	135.289717	'SIO2HL'
	38:	431.86893	43.207971	SIUZHU
	39:	14250.66524	1.000000	'SIO2HL'
25	40:	290.44991	15.459700	3102111
	41:	183.43506	56.245505	'SIO2HL'
	42:	-238.71906	28.322086	0400
	43:	-689.33370	114.792439 28.350285	'SIO2HL'
	44:	-429.48801	1.000000	
30	45:	-258.98856	39.841410	'SIO2HL'
	46:	398.85931	11.000000	
	47:	230.04262 324.81640	49.875208	'STO2HL'
	48:	-854.01841	1.000000	•
	49:	221.87147	18.942210	'SIO2IIL'
	50:	167.65528	16.891234	
35	51:	253.72485	28.225022	'SIO2HL'
	52: 53:	7134.26986	0.790361	
	STO:	INFINITY	5.370968	
	55:	156.41574	37.45869.6	
	56:	425.02539	13.790057	
40	57:	2532.66232	21.354413	'SIO2HL'
	58:	-487.11572	0.100000	AGTOSHI (
*	59:	-754.17801	35.849436	'SIO2HL'
	60:	117.83998	10.996190	'SIO2HL'
	61:	174.62750	35.656142	5102113
45	62:	-1054.34644	0.100000	'CAF2HL'
_	63:	110.05260	64.820400	Con Busi
	64:	4815.31686	0.100000	'CAF2HL'
	65:	241.11586	26.846900 14.154338	
	66:	-465.81838	-0.000247	
50 .	IMG:	INFINITY	-0.00021	
<i>9</i> 0 .				

table 2: wavelength = 193,31 nm

5	Object	Radius 7	Thickness RMD	Glass sort	•
10			:		
	> OBJ:	INFINITY	0.00000		
	101:	INFINITY	35.000000		
15	A02:	443.12451	16.000000		'S102HL'
	403:	-18962.23411	82.000000		
	1O4:	INFINITY	408.713716	•	
	10 5:	INFINITY	0.000000		'SIO2HL'
	406:	513.10831	35.000000		210211
20	101 :	-789.19840	7.958704		'SIO2HL'
, 20	40 8:	-431.08447	15.000000		SIUZHD
	10 9:	2470.39244	39.539157		'SIO2HL'
	1 10:	-305.22015	15.000000		31021111
	J 11:	-2422.57208	38.046226		'SIO2HL'
	从 12:	-202.24219	15.000000		310210
25	4 13:	-372.89974	12.390873	REFL	
	A14:	INFINITY	0.000010	REFL	
	J 15:	277.58610	12.390873	KEPL	'SIO2HL'
	4 16:	372.89974	15.000000 38.046226		3102111
	1 17:	202.24219	15.000000		'SIO2HL'
30	1 18:	2422.57208			0100
	4 19:	305.22015			'SIO2HL'
	λ20:	-2470.39244		•	5200
	\ 21:	431.08447			'SIO2HL'
	122:	789.19840	·		
	A23:	-513.10831			
<i>35</i> .	124 :	INFINITY	·		
•	A25:	INFINITY	•		'SIO2HL'
	A26:	390,52726		}	
, ·.	427:	-683.31437 1069.12804			'SIO2HL'
1	A28:	-1717.09523	-		•
- 40	∤ 29 :	-1/1/.0332	2 23.0.2367	-	

table 2: wavelength = 193,31 nm

5	Object	Radius	Thickness RMD	Glass sort	
			•		• ,
					•
	J 30:	-271.40065	24.662421	'SIO2HL'	
10	4 31:	585.28487	4.258045	'SIO2HL'	
	4 32:	1037.54513	47.522078 1.00000		
	4 33:	-299.20504 1517.35976	14.493847	'SIO2HL'	
	-√34: - √ 35:	-1667.38733	29.793625		
	136:	374.98529	38.496191	'SIO2HL'	:,
15	1 37;	215.15028	58.056542	•	
				'SIO2HL'	
	₹38 :	-244.39173	20.364718	5102.55	
	A39:	-481.59968	1.000000	'SIOZHL'	
	J40:	685.96658	50.000000 124.805511		
20	A41:	-466.91597	26.730825	'SIO2HL'	-
	142: 143:	337.88037 60685.02516	1.000000		
	744:	307.00084	25.717686	'SIO2HL'	
	145:	173.62675	54.501370		
	146:	-283.94563	28.052025	'SIO3HL'	
25	447:	-1327.60130	127.853517		
	A48:	-457,68711	32.289214	'SIOZHL'	
	149 :	-280.72637	1.000000	'SIO2HL'	
	450:	350.95083	33.551443	31022	
	<i>4</i> 51 :	233.87449	11.000000 44.382117	'S102HL'	•
30	λ52:	316.35603 -1117.42550	1.000000	•	
	ス53: ス54:	218.72076	22.816384	'SIO2HL'	
	A 55:	170.60059	13.066780		·
	A 56:	248.49595	27.215517	, SIOSHT,	
	A 57:	2867.70932	-0.636677		•
05	sro:	INFINITY	5.190673	'SIO2HL'	·
35	人 59:	159.10817	37.337945	0202	
	٨ 60:	450.28461	13.813926	*	
	asp K	: 0.000000			
•	TC.	: YES	CUF: 0.000000		- 11 20D3E 31
	A	:0.284543E-09	B :121419E-12	C :294548E-17	D :112803E-21 H :0.000000E+00
40	E	:0.107208E-26	F :0.606134E-30	G :0.000000E+00	H :0.000000E+00
	J	:0.000000E+00			
	1 62 .	1002 00010	56.358019	'SIOZHL'	
	አ61: አ62:	4993.99819 125.35419	8.227596		
4=	762: 763:	178.76516	35.546249	'SIO2HL'	
45	A 64:	-544.56516	0.100000		
	165:	111.13737	65.000000	'CAF2HL'	
	166:	633.24492	0.100000	'CAF2HL'	
	167:	218.73155	30.206802	CAL ZILL	
	168 :	-335.35055	12.082469		
50	IMG:	INFINITY	-0.000503	•	

table 3: wavelength = 193,31 nm

5	Object	Radius	Thic	kness RMD	Giass	sort	i	•
				·. ·		. •	٠.	
				·. ·			•	
				<i>:-</i> •				
10		*		0.00000				
	> OBJ:	INFINITY		35.000000				
	201:	INFINITY	•	21.000000		'SIO2HL'		
	202:	412.00283		82.000000		0100110		
	50 3:	13807.40229		73.169978				
	204:	INFINITY	4	0.000000				
15	205:	INFINITY		16.000000		'SIO2HL'		
	20 6:	-253.51555		27.805541	•			
	207:	-544.16517		16.000000		'SIO2HL'		•
	208:	-205.78974		13.131367				
*	209:	-424.01744 INFINITY		0.000010	REFL			•
`_	210:	282.11038		13.131367	REFL	•		
, 20	211:							
,	ASI	. 0.000000						•
	K	YES	CUF	0.000.00				
	IC		В	:0.163583E-14	С	:0.222395E-19	D	:127469E-23
	A ~	:0,102286E-09	F	:388631E-32	Ğ	:0.000000E+00	н	:0.000000E+00
	E	:0.130171E-27	*	,5000555	_			
25	J	0.0000000000000000000000000000000000000						
	7.0	424.01744		16.000000		'SIO2HL'		
	Z12:	205.78974		27.805541				
	213:	544.16517	•	16.000000		'SIO2HL'		-
	214:	253.51555		530.616842				•
	215:	INFINITY		0.000000				•
30	216:	INFINITY		63.778860				
	Ž17:	636.23394		27.336162	•	'SIO2HL'		
	Ž18:	-774.44237		0.100000				
	Ž 19:	~//4.4427		0.22000		•		

table 3: wavelength = 193,31 nm

5	Object	Radius	Thickness RMD	Glass sort
10		630 4516E	27.867198	'SIO2HL'
	2 20:	638.45165	26.668510	
	2 21:	-950.10950	38.386102	'SIO2HL'
	Z 22:	-332.85587	18.442845	
	· 2 23 :	866.08021	47.039609	'SIO2HL'
15	224:	-1525.57443	1.000000	
	Z 25:	-390.53318 1733 ₋ 78965	28.403565	'SIO2HL'
	Z26:		0.100000	
	227:	-524.35781	16.000000	'SIO2HL'
	Z 28:	835.74339 298.64601	57.500000	·
11	Z 29:	-259.59279	16.000000	'SIO2HL'
20	2 30:	-411.70682	1.000000	
·	Z 31: Z 32:	1128.90538	36.253267	'SIO2HL'
	2 :33:	-477.96774	253.556594	·
	Z 34:	435.03169	32.866003	'SIO2HL'
25	235:	-2559.42430	1.000000	
25	2 36:	275.15076	16.000000	'SIO2HL'
	237:	187.82645	66.000000	
	Z 38:	-296.62496	44.201058	'SIO2HL'
	239:	-690.62720	135.986515	
	240:	4019.70777	21.709054	'SIO2HL'
30	241:	-800.90710	1.000000	
	242:	853.98857	⁻ 50.000000	'SIO2HL'
	-2 43 :	254.20904	12.399910	
•	244:	408.20829	38.016254	'SIO2HL'
	⊋ 45:	-643.03332	1.000000	
35	-2. 46:	228.71372	16.000000	'SIO2HL'
•	247:	175.28033	14.986197	40700111 (
	₹48:	269.82502	31.500000	'SIO2HL'
	249:	20733.22818	-7.061102	
	STO:	INFINITY	8.061102 -	'SIO2HL'
40	₹51:	160.50399	37.926522	210201
40	2. 52:	457.13661	12.706908	'S102IIL'
	2. 53 :	1597.64988	23.273549	3102110
	2 54:	-728.49646	0.100000	'SIO2HL'
	2 55:	-2709.38689	37.761809	3102111
	256:	120.00817	10.277526	'SIO2HL'
45	2 57:	171.38842	38.220630 0.100000	
	2 58:	-2029.55473	64.846281	'CAF2HL'
	3 59 :	116.83775	0.100000	
	2 60 :	1815.17026 212.15910	28.928425	'CAF2HL'
	261:	-501.97805	15.000534	
50	262:	YTINITY	-0.000523	
	IMG:	TMG TMT.1.1	, , , , ,	

table 4: wavelength = 193,31 nm

5	Object	Radius	Thickness RMD	Glass sort	•
	•			•	· ·
10			er e		
15	> 0BJ: 301: 302: 303: 304: 305: 306: 307: 308:	INFINITY INFINITY 434.57513 36267.41000 INFINITY INFINITY -254.30195 -532.25303 -204.79768	0.000000 35.000000 22.000000 82.000000 477.044163 0.000000 16.000000 29.144125 16.000000 13.323325	'SIO2HL' 'SIO2HL'	
•	309: 310: 311: ASP: K :	-421.29373 INFINITY 285.25831 0.000000	0.000010 F 13.323325 F	REFL REFL	
25	Ξ:	YES 0.116419E-09 0.506427E-28 0.000000E+00	CUF: 0.000000 B:0.112957E-14 F:185566E-32	C :937828E-20 G :0.000000E+00	D :466752E-24 H :0.000000E+00
30	312: 313: 314:	421.29373 204.79768 532.25303	16.000000 29.144125 16.000000	'SIO2HL'	-
35	315: 316: 317: 318: 319: 320:	254.30195 INFINITY INFINITY 801.47063 -741.91592 852.20028 -1040.41670	537.666508 0.000000 63.778860 30.675310 0.100000 21.124661 31.707289	'SIO2HL'	
	3 21: 3 22: 3 23:	-1040.410702 -270.54645 600.48250	26.187590 18.319696	'SIO2HL'	

table 4: wavelength = 193,31 nm

5**5**

5	Object	Radius	Thickness RMD	Glass sort	•
	•			. -	
10		·•			
70	324 :	774.95053	41.436216.	'SIO2HL'	
	325:	-355.71105	1.000000 29.490290	'STO2HL'	
	3 26:	1591.83158 -556.23481	53.458289	53.02.12	•
	3 27: 328:	854.87463	16.000000	'SIO2HL'	
15	3 29:	282.30181	54.422763 .		
	330:	-261.43332	24.488537	'SIO2HL'	
•	331:	-411.65692	1.000000		
	332:	1107.48205	37.032421	'SIO2HL'	
	3 33:	-513.59706	246.562860	4.0703171.4	
20	334:	423.57328	28.982815	'SIO2HL'	•
20	3 35:	76613.31446	1.000000 16.00000	'SIO2HL'	
	3 36:	237.50869 171.60021	63.162192		••
	3 37:	-285.36403	50.000000	'SIO2HL'	
	3 38: 339:	-902,91449	95.050310		
	340:	-733.54713	21.388284	'SIO2HL'	
25	311:	-375.20521	1.000000		•
	342:	436.34842	50.00000	'SIO2HL'	
	343:	264.04939	12.000000	482022	
	₹44:	395.02148	37.208539	'SIO2HL'	
	345:	-792.61152	1.000000 20.499145	'SIO2HL'	
30	3 46:	215.61815 165.98868	14.685149	2.40,	•
	347: 348:	248.36356	31.000000	'SIO2HL'	-
	349:	3136.09812	-8.174425		
	STO:	INFINITY	9.174425		, •
	351:	149.01853	41.331450	'S102HL'	
35	352:	363.61783	14.435195		
35	ASP				
	K	: 0.000000	CUF: 0.000000		
		: YES :0,106229E-08	B :233769E-12	C :128409E-17	D :720355E-21
	A E	:0.577731E-25	F :147820E-29	G :0.000000E+00	H :0.000000E+00
	J	:0.000000E+00		· ·	
40	J				
	3 53:	881.72413	29.308297	'SIO2HL'	
	≥ 54:	121.03439	14.172084	'SIO2HL'	•
	3 55 :	207.65180	41.413236	STOSHP	•
	3 56:	-639.91052	0.100000 65.000 0 00	'CAF2HL'	
45	3 57:	123.89834	0.100000		•
	3 58:	609.59778 186.60911	35.732940.	'CAF2HL'	
	3 59 : 3 60 :	-313.58998	15.000087		
	IMG:	INFINITY	-0.000089		
	CODE V>				•
50	CODE V>	wav	•		•

table 5: wavelength = 157,13 nm

5	Object	Radius	Thickness RMD	Glass	s sort		•
			,		. •		•
		•			•		
		•	~ ^ ^ ^ ^				
10	> OBJ:	INFINITY	0.000000				
	401:	INFINITY	34.000000		'CAF2HL'		
	402:	326.89134	18.000000				
	4⊘ 3 :	7134.75200	91.000000 438.917225				•
	404:	INFINITY	0.000000				
	40 5:	INFINITY	22.000000		'CAF2HL'		
15	406:	386,39605	23.000000				
	407:	3173.10800	13.000000	•	'CAF2HL'		
	408:	-263.73446	36.757293			•	
	409:	1274.99700	14.000000		'CAF2HL'		
	410:	-173.05552	12.325630				
· .	411:	-398.57456	0.000010	REFL			
(↔	412:	INFINITY	12.325630	REFL	•		
****	413:	246.26462	14.000000		'CAF2HL'		·
	414:	398.57456	36.757293				
	4 15 :	173.05552	13.000000		'CAF2HL'		
	416:	-1274.99700	23.000000				
	417:	263.73446	22.000000		'CAF2HL'		
25	418:	-3173.10800	0.000000				
	: 19با	-386.39605 INFINITY	435.917225				
	420:	INFINITY	78.197752				•
	421:	INFINITY	60.000000				
	4 22:	INFINITY	-0.037541				
30	423:	305.29233	35.000000		'CAF2HL'		
50	424:						
	ASI	; 0.000000					
	K IC		CUF: 0.00000	0		_	:546921E-21
	A	:983943E-08	B =0.197982E-1	3 C	:0.331141E-17	D H	00+3000000.0:
	E	:0.476298E-25	F - 165982E-2	9. G	:0.000000E+00	л	10.000000
35	J	:0-000000E+00	•	-•			
			- 75 AAAAA				
	425:	-609.90977	175.000000		'CAF2HL'		
	426:	-211.27437	20.000000 1.000000				
()	427:	-296.93430	32.000000		'CAF2HL'		
40	4 28:	918.04784	10.220682	•			
	429:	-450.01625	35.000041		'CAF2HL'		
	4 30:	211.00994	291.880529				
	431:	147.86638	271.000323				

table 5: wavelength = 157,13 nm

50

5	Object	Radius	Thickness RMD	Glass sort	
			•		
10	ASP:	•			
,,	K: IC: A:	. 0.000000	CUF: 0.000000 B:0.375361E-12 F:746588E-30	C :0.202452E-16 D :158059E-22 G :0.000000E+00 H :0.000000E+00	٠.
15	u .		14.999813	'CAF2HL'	
	432: 433:	302.52916 182.15262 325.54311	32.488787 32.000000	'CAF2HL'	. *
•	434: 435:	-472.69366 132.72874	3.402424 19.621815	'CAF2HL'	(;
20	436: 437:	197.27963	19.825000		
25	ASP K	: 0.000000 : YES : 0.132547E-07 : 0.681679E-25 : 0.000000E+00	CUF: 0.000000 B:0.196227E-12 F:0.439118E-29	C :0.495156E-17 D :0.179425E-21 G :0.000000E+00 H :0.000000E+00	
	STO: 439:	INFINITY 1247.88900 -441.06952	30.976200 21.000000 1.000000	'CAF2HL'	
30	441 : 442 : 443 :	106.43847 390.31325 -262.38753	30.279452 17.376730 10.00000	'CAF2HL'	
	444 : 445 :	8245.04000 105.22412	1.000000 35.374148 1.00000	'CAF2HL'	
35	446: 447: 448:	380.86930 131.60165 -9747.89700	30.324916 12.069889	'CAF2HL'	
40	AS K IC A E	:0.179402E-06 :703555E-19	CUF: 0.000000 B:398734E-10 F:0.266200E-22	С :217607E-13 D :0.684630E-16 G :0.000000E+00 H :0.000000E+00	, ()
*	IMG:	INFINITY	-0.000356		

table 6: wavelength = 157,13 nm

	Object	: Radius	Thickness RMD	Glass sort	
	•	,		•	•
			•	•	
10	·			•	
,,,		· · · · · · · · · · · · · · · · · · ·	• •		
	> OBJ:	INFINITY	0.000000	•	
	501:	INFINITY	34.000000		
	SO2:	340.25194	18.000000	'CAF2HL'	•
	SO3:	-23456,66512	91.000000		
15	504	INFINITY	427.039664		
	50 5:	INPINITY	0.00000	•	·
	SO6:	339.11803	22.000000	'CAF2HL'	
	507:	677.92271	23.000000		
	508 :	-270.98695	13.000000	'CAF2HL'	
٥٠-	50 9:	-16554.24766	44.216394		•
	510:	-179.26036	14.000000	'CAF2HL'	
	511:	-499.04921	16.743922		
	512:	INFINITY	0.000010	REFL	
	\$ 13 :	244.48659	16.743922	REFL	
	asp				
25		: 0.000000			
		: YES	CUF: 0.000000	C :130822E-17	D:680466E-22
	A	:837113E-10	B :251110E-13 F :646050E-31		H :0.000000E+00
	£	:12977918-26	F :646050E-31	G :0.000000±+00	n :0:0000005.00
	J	:0.000000E+00			
30	514:	499.04921	14.000000	'CAF2FIL'	•
	Š 15:	179.26036	44.216394		-
	516:	16554.24766	13.000000	'CAF2HL'	
	517:	270.98695	23.000000		
	518:	-677.92271	22.000000	'CAF2HL'	
	Š19:	-339.11803	0.000000		
35	520:	INFINITY	424.039664		
	521:	INFINITY	48.414185	•	
	522:	INFINITY	60000000 - =	-	
	523:	INFINITY	0.000000	(C3 E2 EE (
	524:	709.73646	35.000000	'CAF2EL'	
40	S 25:	-405.70150	1.000000	'CAF2HL'	
-	5 26:	232.80755	20.000000 54.440692	ريد عظام	
	5 27:	383.54136 -399.49382	20.000000	'CAF2HL'	
	528 :	-399.49382. -455.76820	1.000000	Variation	•
	529: 530:	-581.98648	32.000000	'CAF2HL'	
	530: 531:	-449.85046 ·	13.936275		
45	237;		20.7002.3	_	

table 6: wavelength = 157,13 nm

5	Object	Radius	Thickness RMD	Glass sort	•
	\$32: \$33:	834.67326 ·504.57916	35.000041 338.825443	'CAF2HL'	
10	E :-	0.000000 YES .201937E-07 .110440E-24 .000000E+00	CUF: 0.000000 B:0.255796E-12 F:0.456621E-29	C :123108E-17 G :0.000000E+00	D :0.115629E-20 H :0.000000E+00
15	534: 535:	295.96006 178.17958 304.23731	14.999813 32.488787 32.000000	'CAF2HL'	
20	\$36: 537: STO: 538: 539:	-637.25902 INFINITY 160.25766 250.37700	81.513603 -10.161100 19.621815 43.823508	'CAF2HL'	100 100 100 100 100 100 100 100
25 .	AC : E :0 EC :	0.000000 YES .192340E-07 100 .523462E-25 100 .000000E+00	KC: 100 CUF: 0.000000 B:348224E-12 BC: 100 F:0.264881E-29 FC: 100	CCF: 100 C:223569E-16 CC: 100 G:0.000000E+00 GC: 100	D:380011E-21 DC: 100 H:0.000000E+00 HC: 100
30	541:	369.18529	21.000000	'CAF2HL'	100 100
	542: 543: 544: 545:	-739.90155 137.71809 762.01416 -233.76287	1.000000 39.719231 15.339626 10.000000	'CAF2HL'	
35	546: 547: 548: 549: 550:	-1034.38004 151.43369 -21273.43749 127.02508 -4741.44116	1.000000 35.374148 3.512053 44.121911 12.070337	'CAF2HL'	•
40	ASP K		F :0.277302E-2	O C :281077E-	
	IMG:	INFINITY	-0.000337		

table 7: wavelength = 157,13 nm

5	Object	Radius	Thickness RMD	Glas	ss sort		
					•		
	•						•
10	> OBJ:	INFINITY	0.000000			•	
	601:	INFINITY	3 4 .000000				
	€02:	301.23036	18.000000		'CAF2HL'		
	60 3:	9024.85717	91.000000	-			
	ASF		-				
15	ĸ	: 0.000000	•				
	IC	: YES	CUF: 0.000000			_	
	A	:779174E-08	B :0.228326E-12	C	:0.662071E-17	D	:278267E-20
	E	:0.321230E-24	F :133467E-28	G	:0.00000E+00	H	:0.000000E+00
	J	:0.000000E+00					
<u>-0</u>	604:	INFINITY	372.485723				
	60 5:	INFINITY	0.000000				
	606:	329.24390	22.000000		'CAF2HL'		
	60 7:	710.76999	19.293465				
	608:	-293.87906	13.000000		'CAF2HL'		
	60 9 :	-968.05522	32.145450				
25	610:	-127.26575	14.000000		'CAF2HL'		
	611:	-404.63828	12.941473				
	612:	Infinity	0.000010	REFL			
	613:	219.31121	12.941473	REFL			•
	6 14:	404.63828	14.00000		'CAF2HL'		
	615:	127.26575	-32.145450				•
30	6 16:	968.05522	13.000000		'CAF2HL'		
	617:	293.87906	19.293465	•			
	618:	-710.76999	22.000000		'CAF2HL'		•
	6 19:	-329.24390	0.00000				
	6 20:	INFINITY	369.485723				
35	621:	INFINITY	95.013130	-			
35	G 22 :	Infinity	60.000000				
	6 23 :	INFINITY	-0.037541	-			•
	624:	1056.88268	35.000000		'CAF2HL'		
	625 :	-406.34822	175.000000				
	6 26 :	-271.71671	20.000000		'CAF2HL'		
40	627 :	-344.24640	1.000000		'CAF2HL'		
	628:	766.12486	32.000000		CAPARL		
	629:	-1402.78472	10.220682		'CAF2HL'		
	6 30∶	385.79357	35.000041		'CAP Anu'		
	; 31	559.31200	341.919072				

table 7: wavelength = 157,13 nm

5	Object	Radius	Thickness RMD	Glass sort	
			•		•
10	IC A E	. 0.000000	CUF: 0.000000 B:0.579328E-14 F:705924E-31	C :0.860442E-18 G :0.00000E+00	D:644328E-22 H:0.00000E+00
15	6 32: 6 33: 6 34:	232.53878 151.97593 240.71208	14.999813 32.488787 32.000000	'CAFZHL'	
20	635: STO: 636: 637:	2495.46807 INFINITY 153.92754 131.56320	115.579649 -10.161100 19.621815 5.507542	'CAF2HL'	100 100 100 100 100 100 100 100
2Ś	IC A AC E EC J	0.000000 YES :0.298130E-07 : 100 :519344E-24 : 100 :0.000000E+00 : 100	KC: 100 CUF: 0.000000 B:0.555237E-12 BC: 100 F:0.690328E-23 FC: 100	CCF: 100 C:0.829224E-17 CC: 100 G:0.000000E+00 GC: 100	D:0.102908E-20 DC: 100 H:0.000000E+00 HC: 100
30	639:	132.44534	30.378652	'CAF2HL'	100 1 <u>0</u> 00
	6 40: 6 41: 6 42:	1119.94416 120.32786 -709.67342	20.794473 33.748154 11.965434	'CAF2HL'	
35	6 43: 6 44: 6 45: 6 46: 6 47:	-214.74768 3292.43700 108.37386 453.20106 118.78841	7.500000 1.000000 35.374148 1.000000	'CAF2HL' 'CAF2HL'	
	64 8: As	-564.84518 [‡] P:	12.070427		
40	K IC A E J	0.000000 YES :0.192521E-06 :127297E-18 :0.000000E+00	CUF: 0.000000 B:249999E-10 F:0.406332E-22	C :634108E-13 G :0.000000E+00	
	IMG:	INFINITY	-0.000427		

Thickness RMD _ Glass sort

table 8: wavelength = 157,13 nm

Radius

Object

	•	, , , , , , , , , , , , , , , , , , , ,	
			•
-	•	•	•
	•		•
		•	
10		š.	
	•	·.	
	Radius	Thickness RMD Glass sort	CCY THE GLC
	1144144	11(10)(1000) 1(110) (1000) 201(
	> OBJ: INFINITY	0.000000	100 100
	701: THEINITY	34.000000	100 100
15	702: 276.26597	15.000000 'CAF2HL'	0 100
	103: 1021.75438	95.000000	0 100
	ASP:		
	K : 0.000000	KC : 100	
		CUF: 0.000000 CCF: 100	
		B :0.447070E-12 C :0.503629E-18	p :232159E-20
			DC: 0
TO	AC : 0		H :0.000000E+00
	E :0.232819E-24		HC : 100
	EC: 0	FC: 0 GC: 100	116 . 200
	J :0.000000E+00	•	••
	JC: 100		
	• ,		
25	704: INFINITY	423.855836	100 0
25	305: INFINITY	0.00000	100 100
	706: 372.37592	22.000000 'CAF2HL'	0 100
	20 7: 668.85257	37.501319	0 0
	708: -230.27740	13.000000 'CAF2HL'	0 100 '
	-2918.43592	38.093680	0 0
	710: -184.07315	14.000000 'CAF2HL'	0 100
30	711: -413.16131	19.545452	a 0
	712: INFINITY	0,000010 REFL	100 100
	1 12: 248.15084	19.545452 REFL	O PIK .
	.,	14.000000 'CAF2HL'	BIK BIK "
		38.093680	PIK PIK
	132 1	13.000000 'CAF2HL'	PIK PIK
	7 16: 2918.43592		PIK PIK
35	7 17: 230.27740	37.501319	PIK PIK
	718: -668.85257		PIK PIK
] -19: -372,37592	0.000000	100 PIK
	720: INFINITY	405.855836	100 100
	121: INFINITY	27.000000	
	F22: INFINITY	10.680479	
	723: INFINITY	60.000000	
40	124: INFINITY	0.00000	
	725: 434.25844	35.000000 'CAF2HL'	• -
	726: -397.82211	175.000000	0 100

table 8: wavelength = 157,13 nm

5	Object	Radius	Thickness RN	MD Glass sort	
10	ASP: :		20.000000 KC: 100	'CAFZHL'	0 100
.15	IC: A:0.114 AC: E:0.683 EC: J:0.000 JC:	1541E-07 B 0 B 1757E-25 F 0 F	3C ; 0.00000E+00	CCF: 100 C:658251E-17 CC: 0 G:0.000000E+00 GC: 100	D:0.191605E-20 DC: 0 H:0.000000E+00 HC: 100
	729: 46 ASP:	15.97649 51.23130		'CAF2HL'	0 100 0 0
20	IC : A :10: AC : E :0.21: EC :	YES C 1414E-07 E 0 E 6455E-25 E 0 0	BC: 0	C :0.186983E-16	D:170111E-20 DC: 0 H:0.000000E+00 HC: 100
25	331: 4:	28.48297 21.79876 33.21969	10.220682 35.000041 323.036498	'CAF2HL'	0 100 0 100 0 0
30	IC : A :0.67 AC :	YES (0 3083E-08 1 0 1 6831E-25 1	KC: 100 CUF: 0.000000 B: 0.150516E-12 BC: 0 F: 0.126917E-29 FC: 0	CCF: 100 C:0.722292E-17 CC: 0 G:0.000000E+00 GC: 100	D:0.630701E-22 DC: 0 H:0.000000E+00 HC: 100
, 35	734: 1 735: 2 736: -15 737: 1 738: 6	95.44558 43.55672 63.40415 26.30319 .67.78607	14.999813 24.205075 39.902984 3.439634 29.120237 13.299521	'CAF2HL' 'CAF2HL'	0 100 0 0 0 0 0 0
40	ASP: K : 1C : A :0.23 AC :	0.000000 YES 13702E-07 0	KC: 100- CUF: 0.000000 · B:256444E-12 BC: 0	CCF: 100 C :0.855972E-17 CC : 0	D :404743E-20
45	EC :	09335E-24 . 0 00000E+00 100	F :169687E-28 FC : 0	G : 0,000000E+00 GC : 100	H :0.000000E+00 HC : 100
	7-40: -	INFINITY 259.64858 231.31755	29.339697 30.669679 1.374343	'CAFZHL'	100 0 0 0 0 0
50	AC : E :0,4 EC ;	0.000000 YES 47745E-07 0 40576E-24 0	KC : 100 CUF: 0.000000 B :-143625E-11 BC : 0 F :0.000000E+00 FC : 100	CCF: 100 C :0.149412E-15 CC : 0 G :0.000000E+00 GC : 100	DC:103761E-19 DC: 0 H:0.000000E+00 HC: 100
. 55	jc :	100	•		

table 8: wavelength = 157,13 nm

55

	Object	Radius	Thickness RN	ID Glass sort	
10-		u _j .			·
15	AC : E :0 EC :	365.96245 0.000000 YES 233481E-08 0 190478E-24	51.763916 KC: 100 CUF: 0.000000 B:114992E-11 BC: 0 F:0.000000E+00 FC: 100	'CAF2HL' CCF: 100 C:0.787872E-16 CC: 0 G:0.000000E+00 GC: 100	0 0 D:817596E-20 DC: 0 II:0.000000E+00 HC: 100
20	J :0: JC : ₹43:	.000000E+00 100 -578.98949	1.500000		0 100 0 0 .
25 _.	740: 745: ASP: K: IC: A:- AC: E:0 EC: J:0	134.74918 163.80998 0.000000 YES 322326E-07 0 .552969E-25 0.000000E+00	36.384686 0.500000 KC: 100 CUF: 0.000000 B:0.819328E-11 BC: 0 F:0.000000E+00 FC: 100	CAF2HL' CCF: 100 C :0.316811E-15 CC : 0 G :0.000000E+00 GC : 100	D :0.370077E-19 DC: 0 H :0.000000E+00 HC: 100
35	JC : 746: 747: 748: 749: ASP:	100 105.20708 2493.20162 357.29743 -759.96556	35.374148 1.000000 36.324916 12.069863	'CAF2HL'	0 100 0 100 0 100 0 PIM
¹ 40			e de la companya de	e Signal Signal	
45	AC E EC	YES 0.364257E-07 0 780604E-21 0 0.000000E+00	KC: 300 CUF: 0.00000 B:0.139300E-10 BC: 0 F:196532E-24 FC: 0	C :141126E-13	DC 1
	IHG:	INFINITY	0.000137	•	100 0

table 9: wavelength = 157,13 nm

5	Object	Radius	Thickness RM	ID Glass sort	
10			·• •	:	
10	•		• .		
		•			CCY THC GLC
	OBJ:	INFINITY	0.00000		100 100
•	&)1:	INFINITY	34.000000	<u>.</u>	100 100
	902.	251.38730	38.497396	'CAF2HL'	0 0
15	202: 203:	603.00415	000000.00	· •	0 100
	ASP:				
	к :	0.00000	KC: 100	CCF: 100	
	IC:	YES	CUF: 0.000000	CCF: 100 C:0.136116E-17	D :369989E-21
	A :	.124195E-07	B :201050E-12	CC: 0 ·	pc: 0
	AC :	0	BC: 0 F:300137E-29	G :0.00000E+00	H :0.000000E+00
20		.571614E-25		GC: 100	HC: 100.
	EC :	0	FC: 0	GE . 200 .	
÷		.000000E+00			••
	: DĽ	. 100	•		
•	2 O4:	INFINITY	460.459734		100 0
	20 5:	INFINITY	0.00000	•	100 100
25	20 4:	-258.59640	22.000000	'CAF2HL'	0 100
	20 7:	-515.99269	26.483445	•	0 0 100
	20 8:	-403.63140	13.000000	'CAFZHL'	0 100
	80 9:	-92B.08447	37.951900		0 100
	20 9: \$10:	-173.01949	14.000000	'CAFZHL'	0 9
	8 11:	-289.04453	3.697524		•
<i>30</i>	ASP:		KC: 100		•
	к :	0.000000	KC: 100 CUF: 0.000600	CCF: 100	•
	IC:	YES 439665E-08	B :0.442003E-13	C :0.181557E-17	D :148322E-21
	A :-	0	BC: 0	CC: 0	DC: 0
	<i>AC</i> ;	•		•	
35	& 12:	INFINITY		TT.	0
35	2 13:	267.30150	3.607524 RE	:FL	O PIA.
	ASP:				
	к:	0.00000		CCF: 100	
	íc:	YES	CUF: 0.000000 B :0.147481E-13	C :0.128674E-17	D :843005E-22
-	•• •		BC: 0.	cc: 0	DC: U
40	AC :	u			
	814:	289.04453	14,00000	'CAF2HL'	PIK PIK
	ASP:				
	Aut.				

table 9: wavelength = 157,13 nm

5	Object	Radius	Thickness RMD	Glass sort			
	· % :	0.00000	KC: 100 .	• •			
	IC:	YES	COP. C. 44	CCF: 100			
	A :0	.4396658-08		C :181557E-17		48322E-21	
10	AC:		BC: PIK:	CC: bik	DC:	PIK	
•	2 15:	173.01949	37.951900		PIK	PIK	
	2 16:	928.08447	13.000000	'CAF2HL'	PIK	PIK	
	217:	403.63140	26.483445			PIK	
	2 18:	515.99269	22.000000	'CAF2HL'		PIK	,
15	3 19:	258.59640	0.00000	•		PIK	
,5	8 20:	INFINITY	.447.459734			PIK	
	8 21:	INFINITY	60.00000	•	100	100	
	3 22:	INFINITY	15.356414			HMY	
	2 23:	INFINITY	40.00000		100	100	
	824:	INFINITY	0.00000		100	100	
~~	825:	633.39437	35.000000	'CAF2HL'	0	700	
ξO	&≥6 :	-347.37162	119.686124		0	100	
	2 27 :	-211.26446	20.000000	'CAF2HL'	ā	0	
	& 28:	-237.58727	1.055156	. 05 50 177 4	Ö	<u>.</u>	
	2 29 :	550.08434	40.000000	'CAF2HL'	Ö	۵	
	2 30:	-612.80061	40.249917	403 F2 HT 4	ă	100	
05	2 31:	-201.71052	35.000000 -	'CAF2HL'	ŏ	0	
25	& 32:	-322.70560	321.354243	CAF2HL	ō	٥	
•	& 33:	-585.62058	9.084229	. CAF 2110	ā	۵	
	234:	367.59560	18.890606				
	ASP:		KC: 100	-			
	K: IC:		CUF: 0.000000	CCF: 100			_
30		0.290547E-07	B :169007E-12	C :334287E-17		4204221-3	1
30	AC :	_	BC: 0	CC: 0	DC:	o	
		*	·-		Q	.100	•
	& 35:	1157.44840	32.000000	'CAF2HL'	ů	0	
	§ 35 : § 37 :	-274.28444	43.654547	. 63 70117 /	ō	ā	
	£37:	189.47888	45.000000	'CAF2'IL'	ŏ	Ö	
35	8 38:	724.11587	12.838681		100	Ü	
	.≨37 0∶	INFINITY	29.998948	'CAF2HL'	Q	٥	
	. 840:	299.02718	33.232875 12.574830	CAPACIA	٥	0	
	2 41:	1469.50622	31,660134 .	.CAF2HL.	0	a	
	3 42:	161.10860 1679.93121	12.291388		٥	٥	
r S	. € 43 : Æ 44 :	-1595.69234	: 44.999319	- CAF2HL	۵	٥	
40	ASP			•			
	ĸ		KC: 100			,	
		: YES	CUF: 0.000000			.176968E-	30
	A	:831600E-07	B :0.176877E-12.		6 D:- DC:	0	
	AC	: 0	BC: 0	CC: 0	٠.	_	
	2.45	-574.3981	2 1.000000	,		100	100
45	845:	105.0128				100	100
	846:	447.3832				100	100
	847:	518.2801				100	100
	848:	510.2001					
•					٥	PIM	
	3 49:	-590.37066	12.070070	•			
50	ASS					•	
		: 0.000000	KC: 100 CUF: 0.000000	CCF: 100		•.	
	īc	: YES	CUF: 0.000000 B:225496E-10	C :0.111640E-1	-: ۵ ٔ د	.286686E	-17
		:0.117497E-06	BC : 0	CC: O	DC :	٥	
	AC	:- 0		•		•	
55	IMG:	INFINITY	-0.00069		100	0	
22							-

table 10: wavelength = 157,63 nm

Object	Radius	Thickness RMC)(Glass sort		
Reference	Rachius	Thickness	•	Glass	•	
number	Times .	THI F	ems ·	material		
Lac	RDY INFINITY	34.000000		U-LA		
1:	INFINITY	4.000000		•		
1002:	312.33717	18.000000		CYLZ,		
<i>100</i> 3:	9682.90099	B3.000000	REFL	•		
4004: XDE:	1MF 1MITY 0.00000	0.000000 I	208:	0.00000	BHN	*
AOE:	52.000000	BDE: 0.000000	CDE:			
5 :	INFINITY	-414.787259				
·100 6:	-405.55295	-22.000000	•	CAF2'		
1007 : 100 a :	-2462.67101 203.79683	-41.116913 -13.000000		'CAF2'		
4 00 9;	1424.67172	-33.321295				
何10:	176.13502	-14.000000		CAP2		
10 11:	480.49454	-16.561783				•
-10 1.2 :	241.21296	16.561783 i	REFL	'CAF2'		
13: 14:	480.49454 176.13502	33.321295		CAPA		
15:	1424.67172	13.000000		'CAF2'		
15:	203.79683	41.7.16913				
17:	-2462.57101	22.000000		CYLS.		
. 181	-405.55295 Indinity	409.787259 0.000000				•
19: 1020:	INFINITY		rept.			
XDE:	0.00000	0000000 BOY	ZDE		BEN	1
ADE:	38.000000	BDE: 0.000000	CDE	. 0.000000		
M 21:	INFINITY -190.01878	-59,941196 -20,601459		'CAF2'		•
-{0 22 : ASP :	-130.01878	-40,002403	•			
X ;	0.000000					
IC :		CDF: 0.000000	_	:0.352915E-16	D	:-1784951R-21
	0.141974E-07 0.116720B-24	B :0.103665E-12 F :256130E-29		:0.000000#+00	B	:0.000000E+00
	00+3000000.0		-			
10						•
1023: 1024:	-179.90445 -210.09796	-6.322544 -39.346550		'CAF2'	•	•
ASP:		45101000				
	0.000000		•			
IC:		CUF: 0,000000		:336180E-16	ם	.0.379837E-21
	:0.767825E-10 :119676E-24	B :0.1287202-13 F :0.186053E-29	6	:0.000000E+00	H	:0.000000E+00
	0.000000E+00	1 .0.250055= 45	•			
	_					
4025; 4026;	473.11548 3696.82552	-103.837418 -15.000000		'CNF3'		
ASP		22110000				
_	: 0.000000					
	: YES :0.254112E-07	CUP: 0.000000 B:369099E-12		:152523E-16	ם	;-,211663E-22
	10.3934832-25	F :220459E-31		:0.0000002+00	Ħ	00+E000000.0:
	:0.00000E+00					
1027:	-1457.62061	-116.883653 -15.478383		'CM72'		
ન0 28 : નવ 29 :	245.07294 470.01593	-119.415520				
ASP	:					
	0.000000	cm; a.000000				
IC .	; YES :0.248698E-08	CUT: 0.000000 B:133539E-13		:100200E-16	g	:278441E-21
A E	1245690E-35	P :0.118955E-29		:0.00000E+0D	H	
j	:0.000000E+00					-
48.4	1.1.04	-48.407461		CAP2		-
1030: 1031:	-211.14451 390.08349	-41.599722				
10 22:	214.84948	-15.000000		'CAF2'		•
1033:	-152.90981	-22.009325				•
ASE						
. K	: 0.000000	•				

table 10: wavelength = 157,63 nm

5	Object	Radius	Thickness RM	ID.	Glass sort	•	
10			<u>:</u> "				
	•	•		_	•		
15	E :	YES 6718865-07 466831E-25 u.000000E+00	CUF: 0.000000 B:0.227147E-11 F:0.184559E-29	C.	:0.653352B-16 :0.0000005+00	H	:0.531753E 21 :0.000000E+00
	10 34:	-456.24753	-36.555361	-	'CAF2'		
20	40 35: 40 36: 40 37:	231.78386 3335.79137 798.41900	-1.000000 -13.249069 -1.000000		'CAF2 '		
	\$70; 4039;	INFINITY -158.3'/404	-4.032535 -46.695487		'CAF2'		•
	10 40: 10 41: 1042:	-287.83268 -174.28171 -127.11599	-0.999916 -11.999877 -15.767825		'CAF2'		
25	ASP: K: IC: A: E:	0.000000	CUF: 0.000000 B:218987E 11 P:111046E-27	C G	:745527E-16	D H	157B130E-20 :0.000000E+00
30	1043:	-215.90706	-41.405295		'CAF2'		
	1044: 1045: 1045:	241.65885 -92.14326 -251.19562	-1.000000 -44.385959 -2.210034	•	'CAF2'		
		: 0.000000	CUP: 0.00000				
35	A E	: YES :0.901760E-07 :0.127620E-22 :0.000000E+00	B :301574E-11 F :272720E-27	C	:132486E-14 :0.00000E+00	H	:0.194427E-18 :0.000000E+00
40	10 47: 48: 10 49: Asp	-163.12030 INFINITY 551.37429	-46.650069 0.000000 0.000000	er en j	CAF2'		
	TC K	: 0.000000 : YES	CUF: 0.000000	_	0.0347749.15	D	:1007348-16
45	A E J	:743735E-07 :0.533395E-20 :0.000000E+00	B :149540E-10 F :149893E-23	G		Ħ	
	50: 51: IMG:	Infinity Infinity Infinity	-6.000000 -11.999873		'CYES'		

Claims

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- 1. Projection exposure lens with
 - 1.1 an object plane
 - 1.2 optical elements for separating beams

- 1.3 a concave mirror
- 1.4 an image plane
- 1.5 a first lens system arranged between the object plane and the optical elements for separating beams 1.6 a second double passed lens system arranged between the optical elements for separating beams and

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- 1.7 a third lens system arranged between the optical elements for separating beams and the image plane characterized in that
- 1.8 at least one of the lens or mirror surfaces of the first, second or third lens system is aspheric and the numerical aperture NA of the projection exposure lens is 0,7 or greater, preferably 0,8 or greater with a maximum image height exceeding 10 mm.
- 2. Projection exposure lens according to claim 1, characterized in that the second lens system comprises a maximum of five lenses.
- 3. Projection exposure lens with 15
 - 3.1 an object plane
 - 3.2 optical elements for separating beams
 - 3.3 a concave mirror
 - 3.4 an image plane
 - 3.5 a first lens system arranged between the object plane and the optical elements for separating beams
 - 3.6 a second double pass lens system arragend between the optical elements for separating beams and the concave mirror
 - 3.7 a third lens system arranged between the optical elements for separating beams and the image plane characterized in that
 - 3.8 the second lens system comprises a maximum of five lenses.
 - 4. Projection exposure lens according to claim 1-3, characterized in that
 - the second lens system comprises two lenses.
 - 5. Projection exposure lens according to claim 1-4, characterized in that the second lens system comprises three lenses.
 - Projection exposure lens according to claim 1-5, characterized in that the two lenses are negative lenses.
 - 7. Projection exposure lens according to claim 1-6, 40 characterized in that the at least two lenses of the three lenses are negative lenses.
 - Projection exposure lens according to claim 4, characterized in that the distance between the vertices of the two lenses of the second lens system is smaller than 0,6 *diameter, preferably 0,5*diameter of the concave mirror.
 - 9. Projection exposure lens according to claim 5, characterized in that 50 the three lenses consist of a first, a second and a third lens and that the distance between the vertices of the first and the third lens of the second lens system is smaller than 0,6 *diameter, preferably 0,5*diameter of the concave
 - 10. Projection exposure lens according to claim 4, 55 characterized in that the diameter of each of the two lenses is greater than 1.1° diameter, preferably 1,2° diameter of the aperture stop.

- 11. Projection exposure lens according to claim 5, characterized in that the diameter of each of the three lenses is greater than 1.1° diameter, preferably 1,2° diameter of the aperture stop.
- 12. Projection exposure lens according to claim 4, characterized in that the distance between the optical elements for separating beams and the first of the two lenses of the second lens system is greater than 1,5° preferably 1,8° diameter of said lens.
- 13. Projection exposure lens according to claim 5, characterized in that the distance between the optical elements for separating beams and the first of the three lenses of the second lens system is greater than 1,5° preferably 1,8° diameter of said lens.
- 14. Projection exposure lens according to claim 1-13, characterized in that the optical elements for separating beams are comprising a beam splitter or a folding surface.
 - 15. Projection exposure lens according to claim 1-14, characterized in that rms wavefront aberration is less than 20 milliwaves, preferably less than 10 milliwaves.
 - Projection exposure lens according to the claim 1-15, characterized in that the first lens system consists of one lens.

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- Projection exposure lens according to claim 16, characterized in that the one lens of the first lens system is a positive lens.
- 18. Projection exposure lens according to claim 16-17, characterized in that the one lens of the first lens system has at least one aspheric surface.
 - Projection exposure lens according to claim 14-18, characterized in that the surfaces for folding a beam are comprising two folding mirrors.
- 20. Projection exposure lens according to claim 19, characterized in that the folding mirrors are internal surfaces of a prism.
 - Projection exposure lens according to claim 20, characterized in that the prism material has an refractive index greater than 1, 4.
 - 22. Projection exposure lens according to claim 21, characterized in that the prism material has an expansion coefficient smaller than 10⁻⁶K⁻¹ in the temperature region -20° C to +300° C.
- 23. Projection exposure lens according to claim 19-22, characterized in that the surface of the folding mirrors are coated with reflection enhancing thin films.
 - Projection exposure lens according to claim 19-23, characterized in that the folding mirrors comprise at least one aspheric surface.
 - 25. Projection exposure lens according to claim 1-24, characterized in that the second lens system and the concave mirror are arranged along an unfolded optical axis.
- 26. Projection exposure lens according to claim 25,55 characterized in that the folding mirrors are arranged in the region where the optical axis of the first lens system and the second lens system crosses.
 - 27. Projection exposure lens according to claim 19-26,

characterized in that the folding angle deviates from 90° such that at the lenses of the second double passed lens system and the concave mirror are more distant from the object plane than the first lens of the first lens system is.

28. Projection exposure lens according to claim 1-28, characterized in that the projection exposure lens comprises an intermediate image.

29. Projection exposure lens according to claim 28, characterized in that the intermediate image is situated in the third lens system.

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30. Projection exposure lens according to claim 28, characterized in that the intermediate image is situated between the optical elements for separating the beams and the first lens of the third lens system.

 Projection exposure lens according to claim 1-30, characterized in that the third lens system comprises the aperture stop.

20 32. Projection exposure lens according to claim 31, characterized in that the third lens system comprises a long drift space without lenses located between the intermediate image and the aperture stop.

33. Projection exposure lens according to claim 31, characterized in that the drift section between the intermediate image and the aperture stop without lenses is greater than 25 % of the distance between the optical elements for separating beams and the image plane.

34. Projection exposure lens according to claim 28-33, characterized in that within 50% of the distance between the intermediate Image and the image plane beginning with the intermediate image in the third lens system at maximum 4 lenses are located.

- 35. Projection exposure lens according to claim 32-34, characterized in that the lenses of the third lens system are density packed between the aperture stop and the image plane.
- **36.** Projection exposure lens according to claim 28-35, characterized in that the plane of the intermediate image is freely accessible.
- 37. Projection exposure lens according to claim 36,40 characterized in that in the plane of the intermediate image a field stop is located.
 - **38.** Projection exposure lens according to claim 1-37, characterized in that the subsystem composed of the second lens system and the concave mirror comprises an aspheric surface.
 - 39. Projection exposure lens according to claim 38, characterized in that the lens of the second lens system next to the concave mirror comprises an aspheric surface.
- 40. Projection exposure lens according to claim 38-39,50 characterized in that the concave mirror comprises an aspheric surface.
 - 41. Projection exposure lens according to claim 39-40, characterized in that the lens next to the concave mirror comprises an aspheric surface, which is situated opposite to the surface of the concave mirror.
 - 42. Projection exposure device, according to claim 41, characterized in that the concave mirror comprises an aspheric surface.

- 43. Projection exposure lens according to claim 38-42, characterized in that a aperture stop is situated in the third lens system and the condition h/φ >1.2 for one or more of the aspheric surfaces is fullfilled, where h is the height at each lens surface of the light beam that is assumed to be emitted from the intersection of the optical axis of the object plane and passes through the lens surface with the maximum numerical aperture and φ is the radius of the diaphragm of the aperture in the third lens group.
- 44. Projection exposure lens according to claim 1-43, characterized in that at least one surface of the lenses of the third lens system is aspheric.
- 45. Projection exposure lens according to claim 44, characterized in that at least one aspheric surfaces of the lenses of the third lens system is located before the aperture plane and at least one behind the aperture plane.
 - **46.** Projection exposure lens according to claim 44-45, characterized in that one of the surface of the lens next to the image plane is aspheric.
 - 47. Projection exposure lens according to claim 1-46, characterized in that all lenses of the projection exposure lens are made of the same material.
 - 48. Projection exposure lens according to claim 1-47, characterized in that the lenses are made of a first material and of a second material, wherein no more than four, preferably no more than three lenses are made of said second material.
 - 49. Projection exposure lens according to one of the claims 47 or 48, characterized in that the first material and/or second material is quartz glass and/or LiF and/or CaF₂ and/or BaF₂ or another fluoride crystal.
 - 50. Projection exposure lens according to claim 49 characterized in that depending from the wave length of light travelling through the projection exposure lens the following material is used:

 $180 < \lambda < 250$ nm: quartz and/or CaF₂ $120 < \lambda < 180$ nm: CaF₂ and/or BaF₂

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- 51. Projection exposure lens according to claim 1-50, characterized in that the third lens system is composed of a field lens group, an intermediate correcting lens group and a focussing lens group.
 - **52.** Projection exposure lens according to claim 51, characterized in that the third lens system comprises

said field lens group is of positive refractive power said intermediate correcting lens group is of positive or negative refractive power said focussing lens group is of positive refractive power.

- 45 53. Projection exposure lens according to claim 1-52, characterized in that at least one -+power doublet with a negative power lens and a positive power lens in this sequence from the object side is arranged in said third lens system.
- 54. Projection exposure lens according to claim 1-53, characterized in that the projection exposure system comprises a intermediate image and the imaging ratio between the object plane and the intermediate image plane is greater than 0.90, but different from unity.
 - 55. Projection exposure lens according to claim 1-54, characterized in that the projection exposure system comprises a intermediate image and the third lens system comprises at least a pair of menisci, the convex surface of the intermediate-image-side meniscus facing to the intermediate image, the convex surface of the other facing oppositely.
 - 56. Projection exposure lens according to claim 51-55, characterized in that said at least one pair of menisci is arranged

in said intermediate correcting lens group.

- Projection exposure lens according to claim 51-55, characterized in a -+power doublet is arranged in said focussing lens group.
- 58. Projection exposure lens according to claim 53-57, characterized in that one of said -+power doublets is arranged next to the aperture plane in the third lens group.
- 59. Projection exposure lens according to claims 1-58, characterized in that the longitudinal chromatic aberration is
 10 less than 0.015 μm per a band width of 1 pm at 193 nm.
 - **60.** Projection exposure lens according to claim 1-59, characterized in that the longitudinal chromatic aberration is less than 0.05 μm per band width of 1 pm at 157 nm.
- 15 61. Projection exposure lens according to claim 1-60, characterized in that it is both side telecentric.
 - 62. Projection exposure apparatus comprising
 - an UV-laser light source
 - an illuminating system

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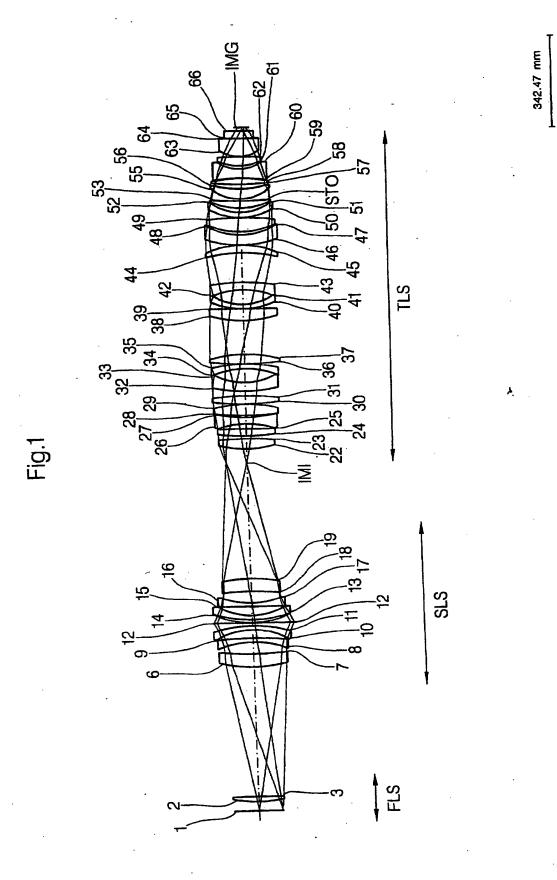
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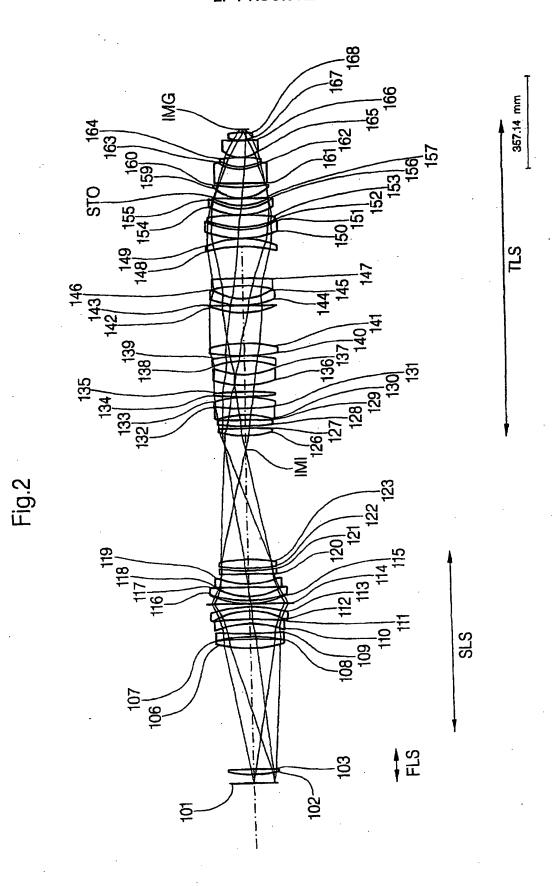
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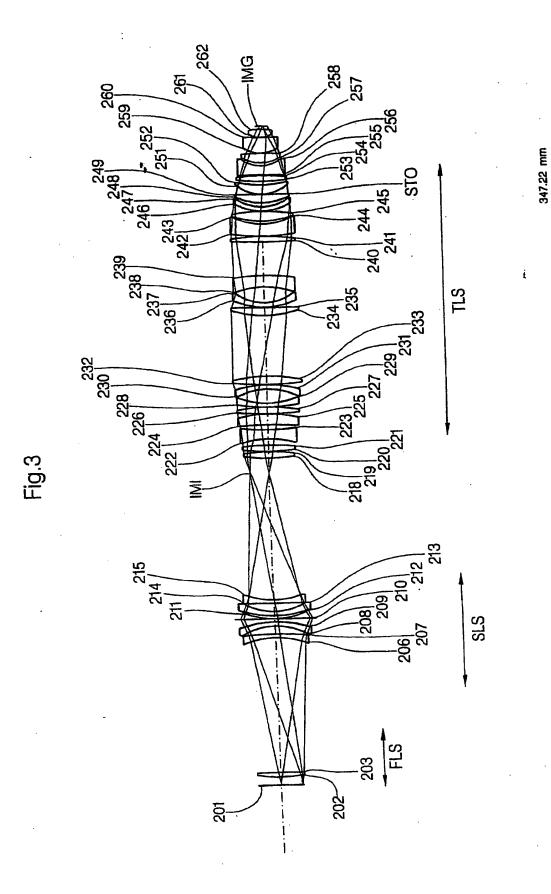
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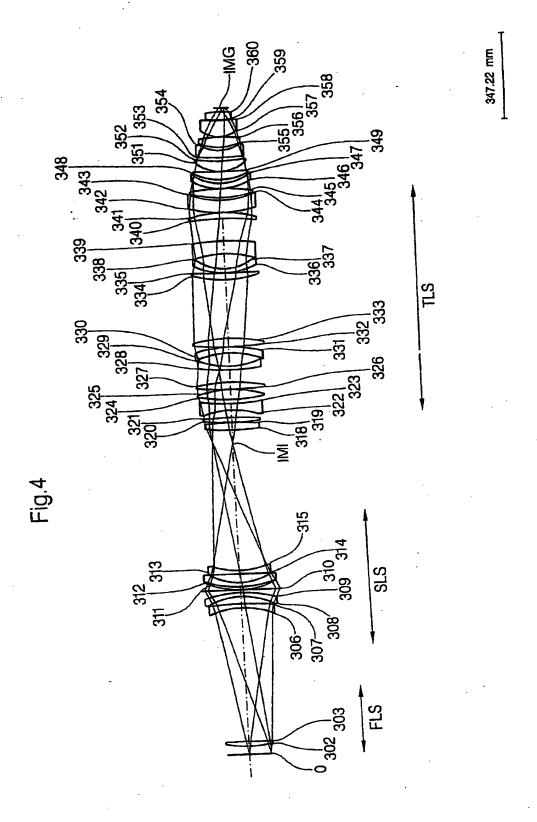
- a mask handling and positioning system
- a projection exposure lens according to at least one of claims 1 to 61
- a wafer handling and positioning system.
- 63. A method of producing microstructured devices by lithography making use of a projection exposure apparatus according to claim 62.
 - **64.** A method according to claim 63, characterized in that use is made of step- and repeat, scanning or stitching exposure schemes.



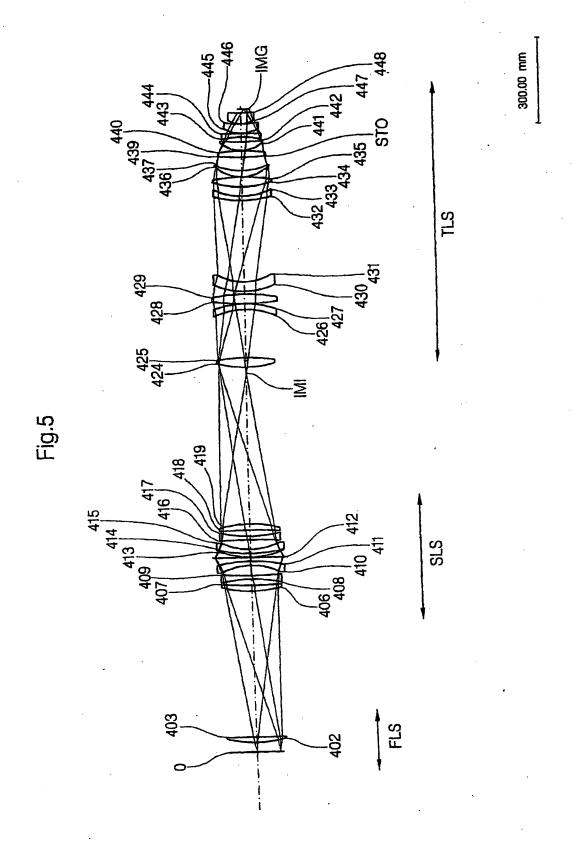


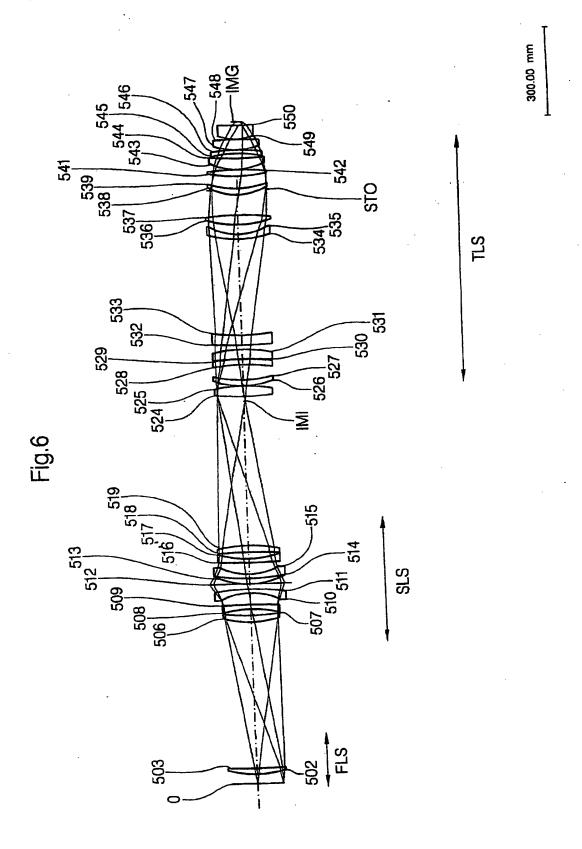


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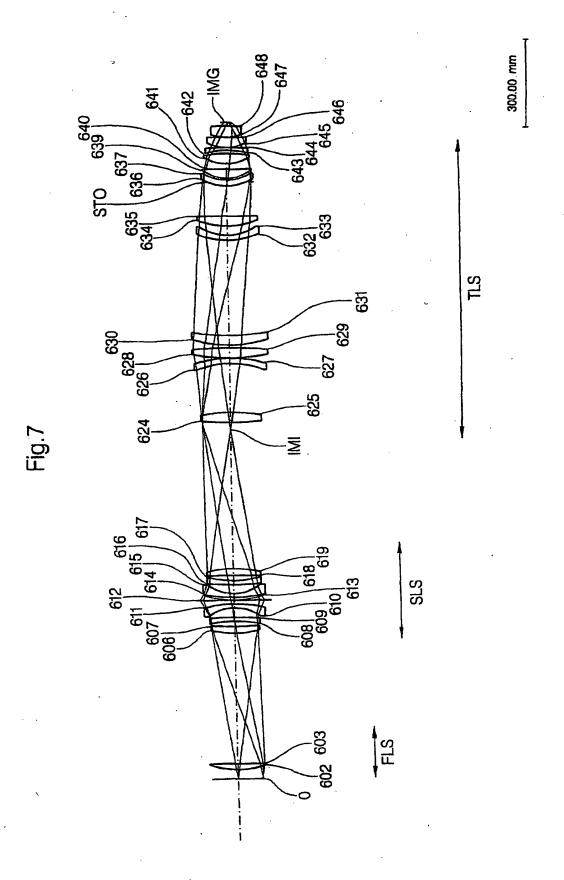
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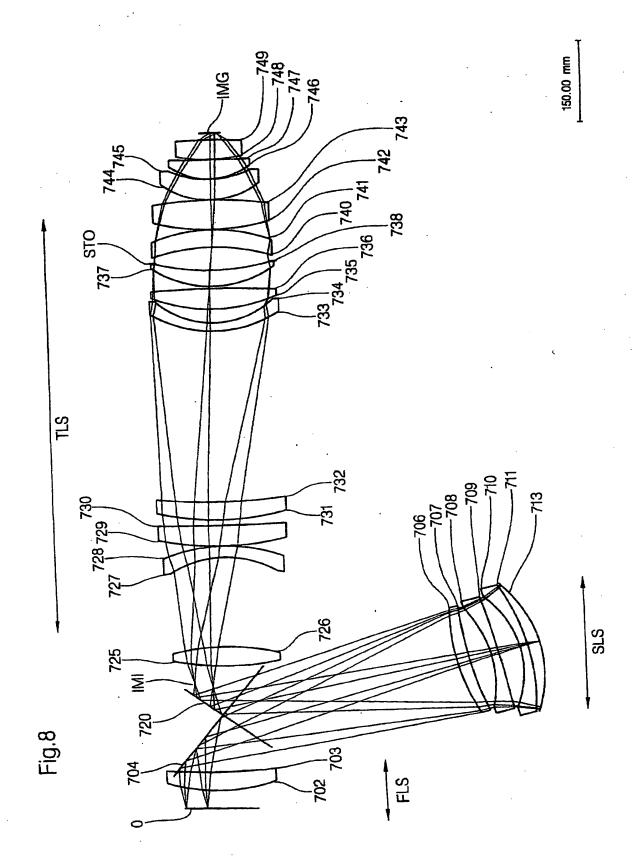


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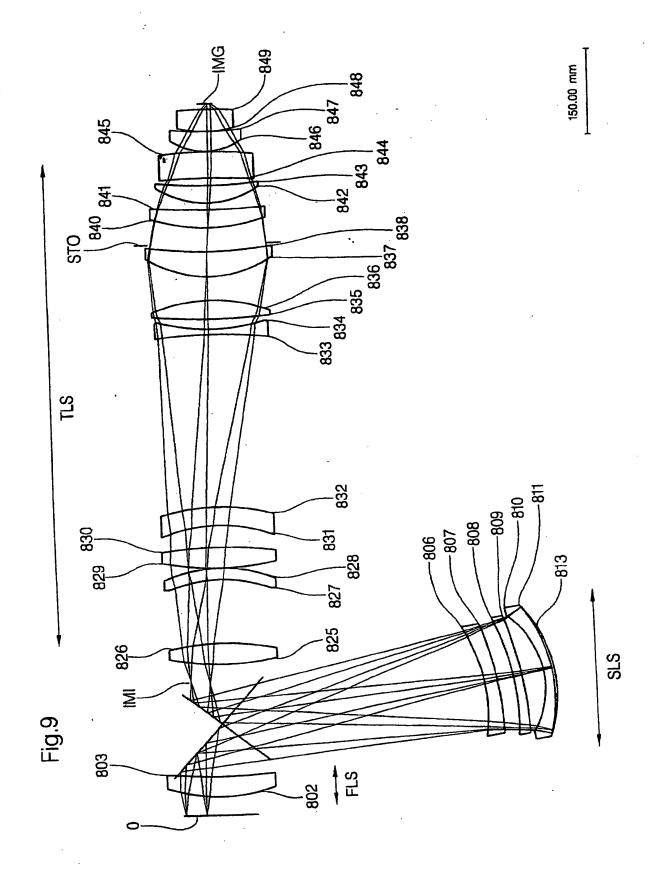
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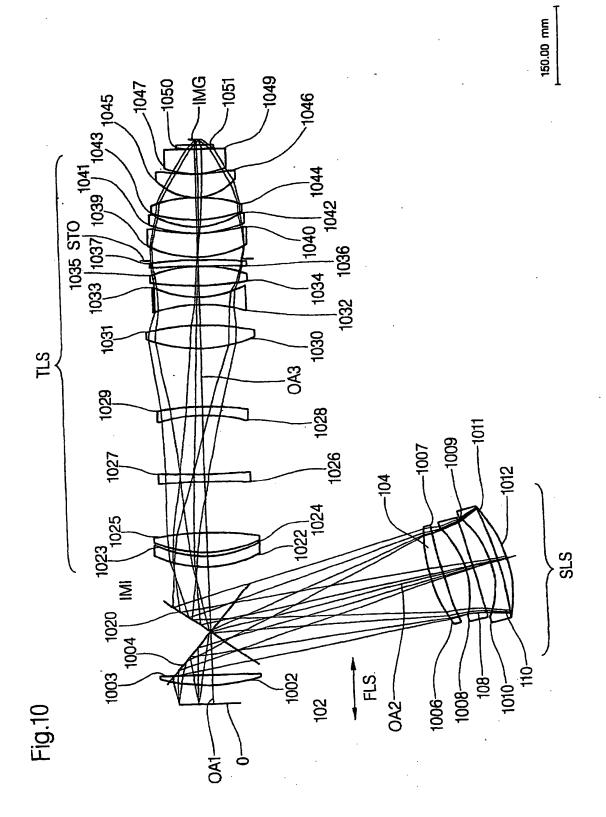


Fig.11

